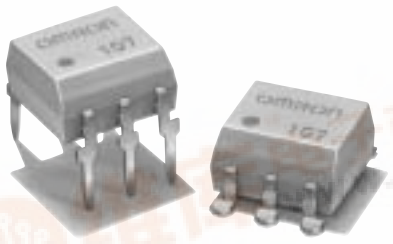
OMRON

MOS FET Relays

G3VM-61B1/E1

Analog-switching MOS FET Relay for High Switching Currents, with Dielectric Strength of 2.5 kVAC between I/O.

- Upgraded G3VM-61 B/E Series.
- Switches minute analog signals.
- Leakage current of 1 μA max. when output relay is open.



NEW Approval pending

Note: The actual product is marked differently from the image shown here.

■Application Examples

- Measurement devices
- Security systems
- Amusement machines

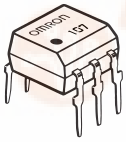
■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	PCB terminals	60 VAC	G3VM-61B1	50	---
	Surface-mounting terminals		G3VM-61E1		
			G3VM-61E1(TR)	---	1,500

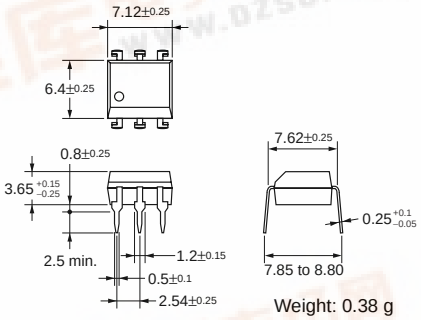
■Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-61B1

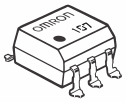


Note: The actual product is marked differently from the image shown here.



Weight: 0.38 g

G3VM-61E1



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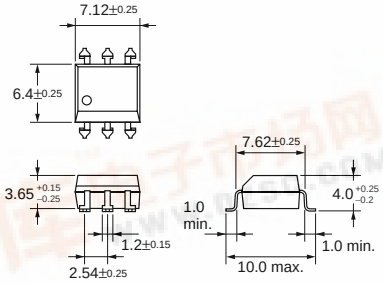
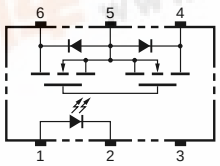


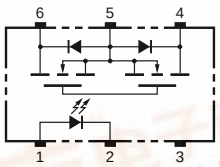
Weight: 0.38 g

■Terminal Arrangement/Internal Connections (Top View)

G3VM-61B1

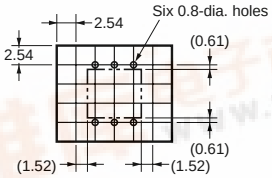


G3VM-61E1



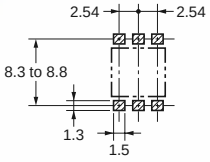
■PCB Dimensions (Bottom View)

G3VM-61B1



■Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-61E1

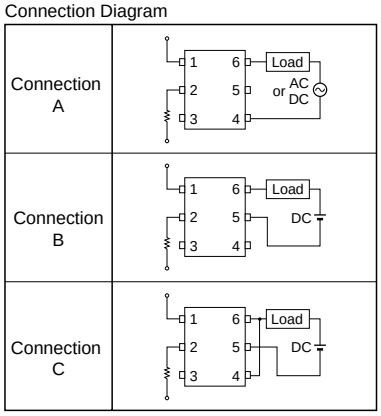


■ Absolute Maximum Ratings (Ta = 25°C)

Item			Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current		I_F	50	mA	
	Repetitive peak LED forward current		I_{FP}	1	A	100 μs pulses, 100 pps
	LED forward current reduction rate		Δ I_F/°C	–0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage		V_R	5	V	
	Connection temperature		T_j	125	°C	
Output	Output dielectric strength		V_{OFF}	60	V	
	Continuous load current	Connection A	I_O	500	mA	
		Connection B		500		
		Connection C		1,000		
	ON current reduction rate	Connection A	Δ I_{ON}/°C	–0.5	mA/°C	Ta ≥ 25°C
		Connection B		–0.5		
		Connection C		–10.0		
	Connection temperature		T_j	125	°C	
Dielectric strength between input and output (See note 1.)			V_{I-O}	2,500	Vrms	AC for 1 min
Operating temperature			T_a	–40 to +85	°C	With no icing or condensation
Storage temperature			T_{stg}	–55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			---	260	°C	10 s

Note: **1.** The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

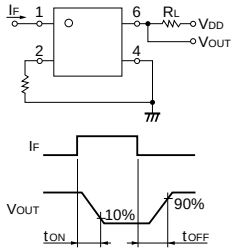
Connection Diagram



■ Electrical Characteristics (Ta = 25°C)

Item			Symbol	Minimum	Typical	Maximum	Unit	Measurement conditions
Input	LED forward voltage		V_F	1.0	1.15	1.3	V	I_F = 10 mA
	Reverse current		I_R	---	---	10	μA	V_R = 5 V
	Capacity between terminals		C_T	---	30	---	pF	V = 0, f = 1 MHz
	Trigger LED forward current		I_{FT}	---	1.6	3	mA	I_O = 500 mA
Output	Maximum resistance with output ON	Connection A	R_{ON}	---	1	2	Ω	I_F = 5 mA, I_O = 500 mA
		Connection B		---	0.5	1	Ω	I_F = 5 mA, I_O = 500 mA
		Connection C		---	0.25	---	Ω	I_F = 5 mA, I_O = 1,000 mA
	Current leakage when the relay is open		I_{LEAK}	---	---	1.0	μA	V_{OFF} = 60 V
Capacity between I/O terminals			C_{I-O}	---	0.8	---	pF	f = 1 MHz, Vs = 0 V
Insulation resistance			R_{I-O}	1,000	---	---	MΩ	V_{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time			tON	---	0.8	2.0	ms	I_F = 5 mA, R_L = 200 Ω, V_{DD} = 20 V (See note 2.)
Turn-OFF time			tOFF	---	0.1	0.5	ms	

Note: **2.** Turn-ON and Turn-OFF Times



■ Recommended Operating Conditions

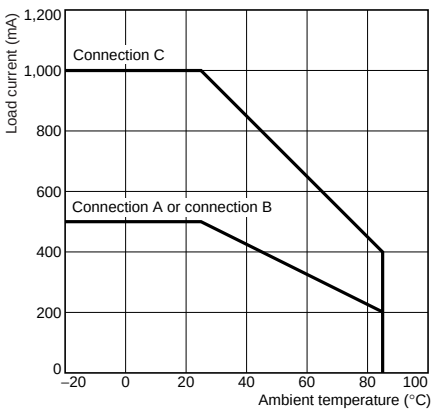
Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V_{DD}	---	---	48	V
Operating LED forward current	I_F	5	7.5	25	mA
Continuous load current	I_O	---	---	500	mA
Operating temperature	T_a	– 20	---	65	°C

■ Engineering Data

Load Current vs. Ambient Temperature

G3VM-61B1(E1)



■ Safety Precautions

Refer to page 6 for precautions common to all G3VM models.